

To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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Notice

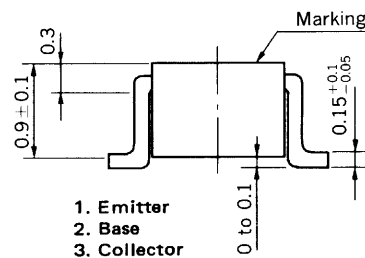
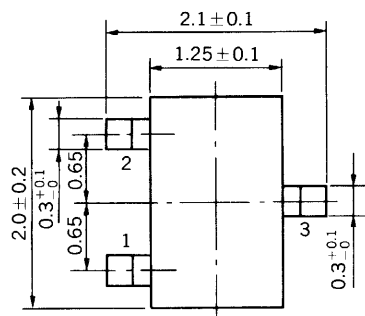
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(Note 2) “Renesas Electronics product(s)” means any product developed or manufactured by or for Renesas Electronics.

HIGH SPEED SWITCHING
PNP SILICON EPITAXIAL TRANSISTOR

PACKAGE DIMENSIONS
in millimeters



FEATURES

- High Speed Switching : $t_{on} = 9.0 \text{ ns TYP.}$
 $t_{off} = 19.0 \text{ ns TYP.}$
- High f_T : $f_T = 1\,800 \text{ MHz TYP.}$
- Low C_{ob} : $C_{ob} = 2.0 \text{ pF TYP.}$
- Complementary to 2SC4176

ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Current ($T_a = 25^\circ\text{C}$)

Collector to Base Voltage	V_{CBO}	-15	V
Collector to Emitter Voltage	V_{CEO}	-15	V
Emitter to Base Voltage	V_{EBO}	-4.5	V
Collector Current (DC)	I_C	-50	mA

Maximum Power Dissipation

Total power Dissipation at 25°C Ambient Temperature	P_T	150	mW
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Maximum Temperatures

Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I_{CBO}			-100	nA	$V_{CB} = -8.0 \text{ V}, I_E = 0$
Emitter Cutoff Current	I_{EBO}			-100	nA	$V_{EB} = -3.0 \text{ V}, I_C = 0$
DC Current Gain	h_{FE1}^*	30	70			$V_{CE} = -1.0 \text{ V}, I_C = -1.0 \text{ mA}$
DC Current Gain	h_{FE2}^*	50	80	150		$V_{CE} = -1.0 \text{ V}, I_C = -10 \text{ mA}$
Collector Saturation Voltage	$V_{CE(sat)}^*$		-0.09	-0.20	V	$I_C = -10 \text{ mA}, I_B = -1.0 \text{ mA}$
Base Saturation Voltage	$V_{BE(sat)}^*$		-0.80	-0.95	V	$I_C = -10 \text{ mA}, I_B = -1.0 \text{ mA}$
Gain Bandwidth Product	f_T	800	1800		MHz	$V_{CE} = -10 \text{ V}, I_E = 10 \text{ mA}$
Output Capacitance	C_{ob}		2.0	3.0	pF	$V_{CB} = -5.0 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$
Turn-on Time	t_{on}		9.0	20	ns	See Test Circuit
Storage Time	t_{stg}		16	40	ns	
Turn-off Time	t_{off}		19	40	ns	

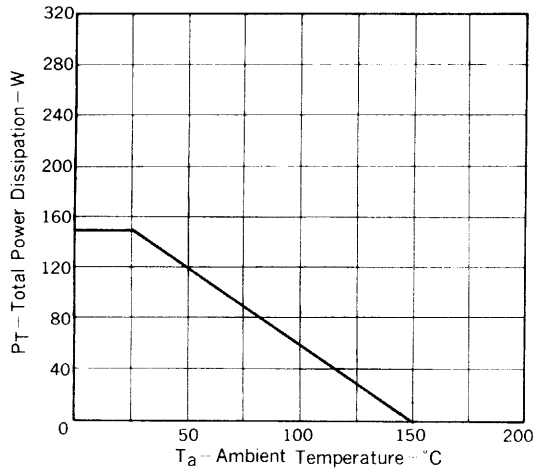
* Pulsed: $PW \leq 350 \mu\text{s}$, Duty Cycle $\leq 2\%$

h_{FE2} Classification

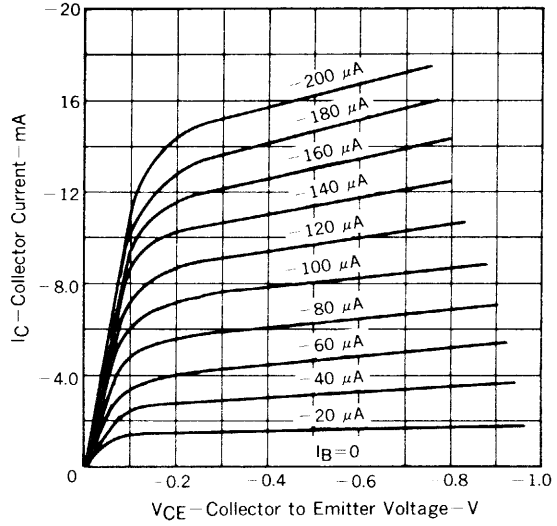
Making	Y33	Y34
h_{FE2}	50 to 100	75 to 150

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

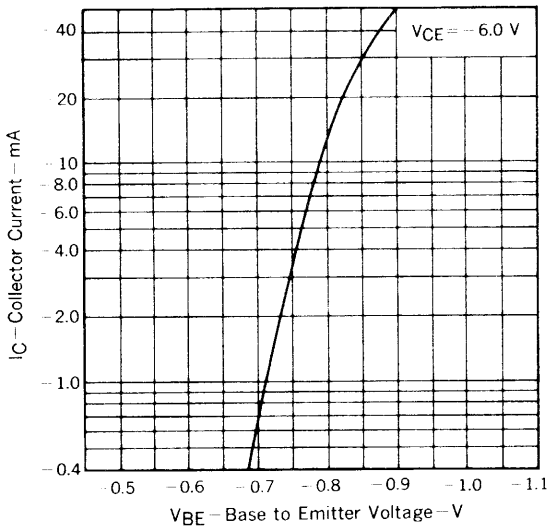
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



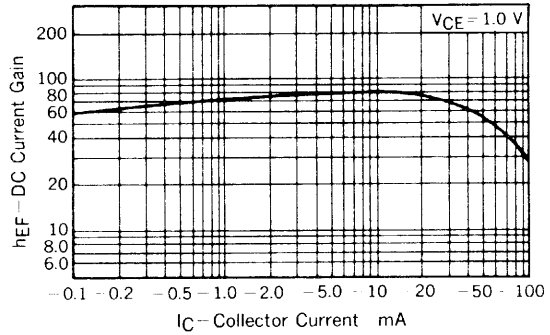
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



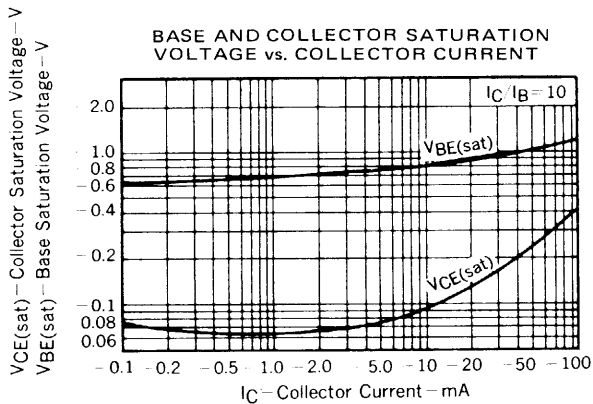
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



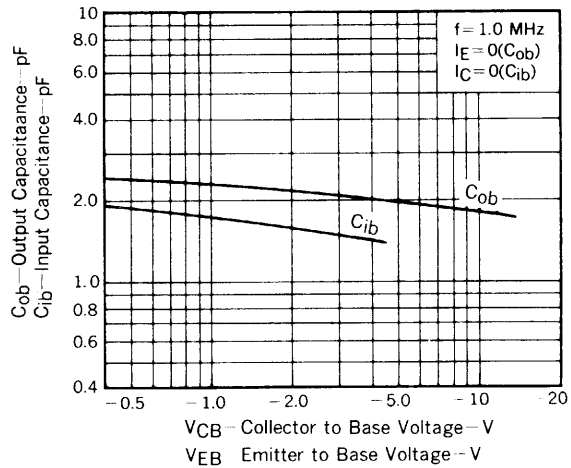
DC CURRENT GAIN vs. COLLECTOR CURRENT



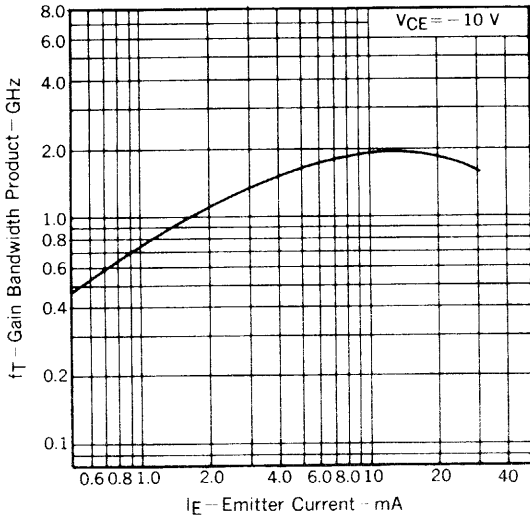
BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



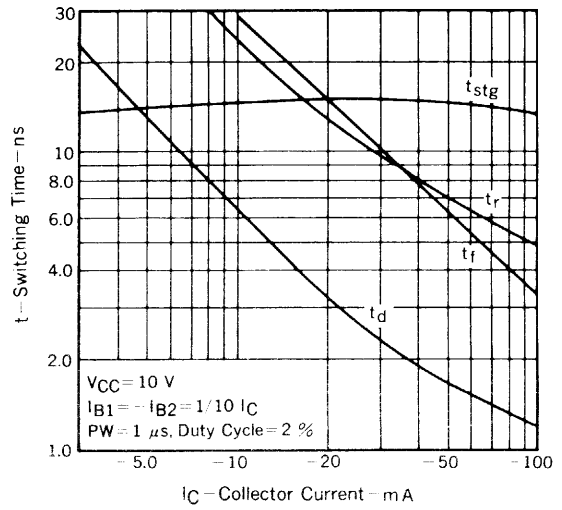
INPUT AND OUTPUT CAPACITANCE vs. REVERSE VOLTAGE



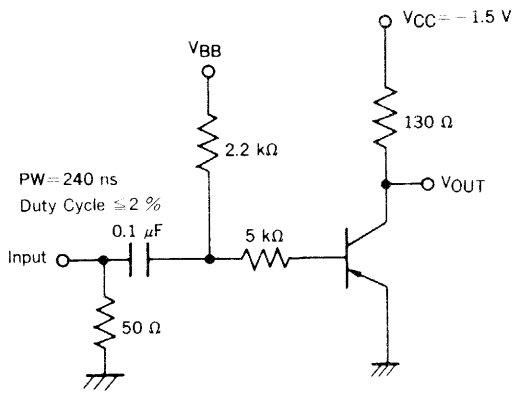
GAIN BANDWIDTH PRODUCT vs. EMITTER CURRENT



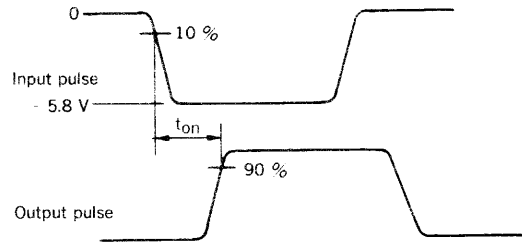
SWITCHING TIME vs. COLLECTOR CURRENT



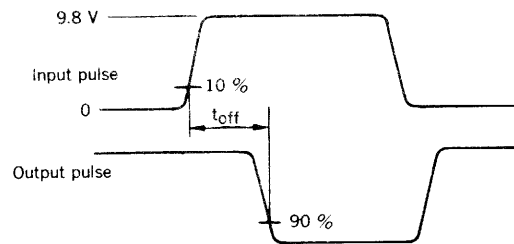
SWITCHING TIME TEST CIRCUIT



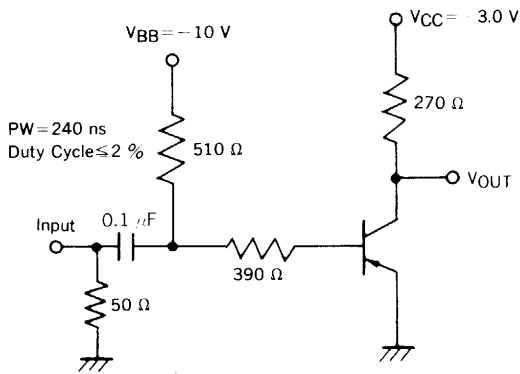
t_{on} , t_{off} Switching



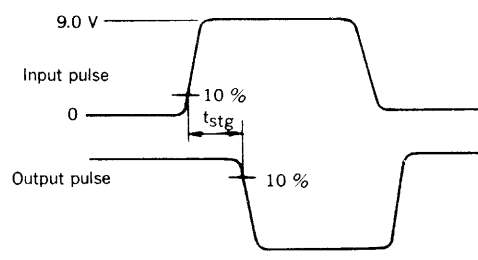
t_{on} Voltage Waveforms ($V_{BB} = \text{GROUND}$)



t_{off} Voltage Waveforms ($V_{BB} = -8.0 \text{ V}$)



t_{stg} Switching



t_{stg} Voltage Waveforms

